

C3D02060A-Silicon Carbide Schottky Diode

Z-RECTM RECTIFIER

 $\mathbf{V}_{\mathsf{RRM}} = 600 \ \mathsf{V}$

 $\mathbf{I}_{\mathsf{F}(\mathsf{AVG})} = 2 \mathsf{A}$

 $Q_c = 4.8 \text{ nC}$

Features

- 600-Volt Schottky Rectifier
- Optimized for PFC Boost Diode Application
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

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Package

TO-220-2

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies
- Power Factor Correction
 - Typical PFC P_{out}: 300W-450W



Part Number	Package	Marking	
C3D02060A	TO-220-2	C3D02060	

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	600	V		
V_{RSM}	Surge Peak Reverse Voltage	600	V		
V _{DC}	DC Blocking Voltage	600	V		
$I_{\text{F(AVG)}}$	Average Forward Current	2.0	А	T _c <160°C	
\mathbf{I}_{FRM}	Repetitive Peak Forward Surge Current	12.0 9.0	А	T_c =25°C, t_p =10 mS, Half Sine Wave D=0.3 T_c =110°C, t_p =10 mS, Half Sine Wave D=0.3	
\mathbf{I}_{FSM}	Non-Repetitive Peak Forward Surge Current	21 19	А	T_c =25°C, t_p =10 mS, Half Sine Wave D=0.3 T_c =110°C, t_p =10 mS, Half Sine Wave D=0.3	
\mathbf{I}_{FSM}	Non-Repetitive Peak Forward Surge Current	65	А	T_c =25°C, t_p =10 μ S, Pulse	
P _{tot}	Power Dissipation	39.5 17	w	T _c =25°C T _c =110°C	
$T_{_{\mathtt{J}}}$, $T_{_{\mathtt{stg}}}$	Operating Junction and Storage Temperature	-55 to +175	°C		
	TO-220 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	



Electrical Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.5 1.8	1.7 2.4	V	$I_F = 2 \text{ A } T_J = 25^{\circ}\text{C}$ $I_F = 2 \text{ A } T_J = 175^{\circ}\text{C}$	
I _R	Reverse Current	10 20	50 100	μΑ	$V_R = 600 \text{ V } T_J = 25^{\circ}\text{C}$ $V_R = 600 \text{ V } T_J = 175^{\circ}\text{C}$	
Q _c	Total Capacitive Charge	4.8		nC	$V_R = 600 \text{ V, } I_F = 2A$ $di/dt = 500 \text{ A/}\mu\text{S}$ $T_J = 25^{\circ}\text{C}$	
С	Total Capacitance	120 12 11		pF	$V_R = 0 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 200 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 400 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$	

Note:

Thermal Characteristics

Symbol	Parameter	Тур.	Unit
$R_{_{ heta JC}}$	TO-220 Package Thermal Resistance from Junction to Case	3.8	°C/W

Typical Performance

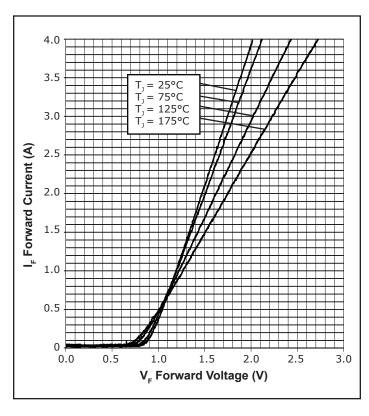


Figure 1. Forward Characteristics

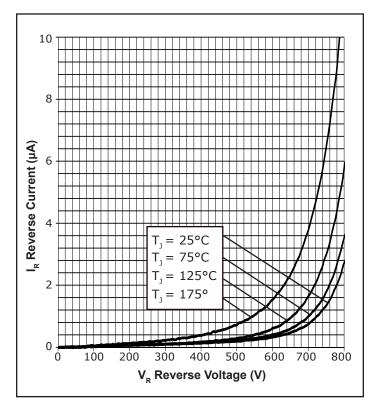


Figure 2. Reverse Characteristics

^{1.} This is a majority carrier diode, so there is no reverse recovery charge.



Typical Performance

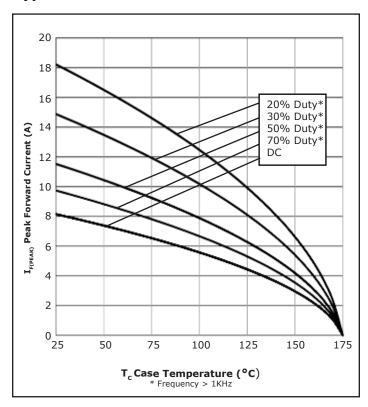
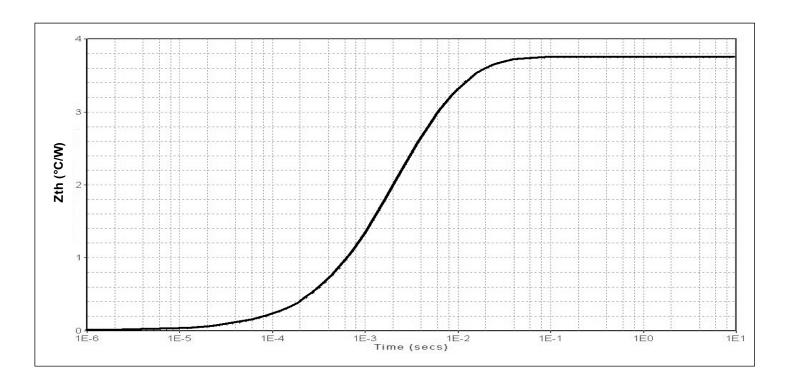


Figure 3. Current Derating

Figure 4. Capacitance vs. Reverse Voltage



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Figure 5. Transient Thermal Impedance



Typical Performance

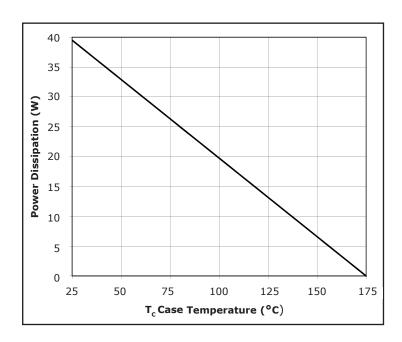
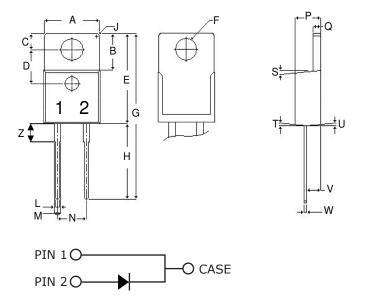


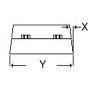
Figure 6. Power Derating



Package Dimensions

Package TO-220-2





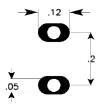
POS	Inc	hes	Millimeters		
POS	Min	Max	Min	Max	
А	.381	.410	9.677	10.414	
В	.235	.255	5.969	6.477	
С	.100	.120	2.540	3.048	
D	.223	.337	5.664	8.560	
Е	.590	.615	14.986	15.621	
F	.143	.153	3.632	3.886	
G	1.105	1.147	28.067	29.134	
Н	.500	.550	12.700	13.970	
J	R 0.	197	R 0.197		
L	.025	.036	.635	.914	
М	.045	.055	1.143	1.397	
N	.195	.205	4.953	5.207	
Р	.165	.185	4.191	4.699	
Q	.048	.054	1.219	1.372	
S	3°	6°	3°	6°	
Т	3°	6°	3°	6°	
U	3°	6°	3°	6°	
V	.094	.110	2.388	2.794	
W	.014	.025	.356	.635	
Х	3°	5.5°	3°	5.5°	
Y	.385	.410	9.779	10.414	
Z	.130	.150	3.302	3.810	

NOTE:

1. Dimension L, M, W apply for Solder Dip Finish



Recommended Solder Pad Layout



TO-220-2

Part Number	Package	Marking	
C3D02060A	TO-220-2	C3D02060	

Diode Model

$$Vf_T = V_T + If *R_T$$

$$V_T = 0.98 + (T_J^* -1.7*10^{-3})$$

 $R_T = 0.21 + (T_J^* 1.71*10^{-3})$

Note: T_i = Diode Junction Temperature In Degrees Celcius

"The levels of environmentally sensitive, persistent biologically toxic (PBT), persistent organic pollutants (POP), or otherwise restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2002/95/EC on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS), as amended through April 21, 2006.

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, air traffic control systems, or weapons systems.

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